## 1 Lab Introduction

In this lab we will be characterizing some of the device parameters of bipolar junction tranistors (BJTs). The learning goals are listed below:

- 1. Understand large signal models of NPN and PNP transistors, including regions of operation.
- 2. Relate large signal measurements of BJT behavior to small signal measurements.
- 3. Get practice biasing both NPN and PNP BJTs.

References: Hays and Horowitz Lab Manual 94, 97

## 2 Measurements of BJT Parameters

- 1. Measure the diode drop across the base-emitter and collector-base diodes of a 2N3904 diode using the diode mode of the multimeter. Explain why the collector-base diode drop is slightly smaller than the base-emitter drop. Hays and Horowitz has a relevant explanation on page 94.
- 2. Measure the  $\beta$ ,  $g_m$ ,  $V_{ce,sat}$  and  $r_{\pi}$  of a 2N3904 transistor. Note that measuring small signal quantities requires taking the ratio of two small signal Voltages and currents; in this class measuring  $g_m$  means taking the ratio of  $i_c$  over  $v_b$ . (Though if you're asked to calculate  $g_m$ , you have options:  $I_C/\phi_t$ ,  $beta/r_{pi}$ , etc.). Vary the collector current over at least the three decades from 100µA to 100mA when measuring these quantities. Be careful not to saturate your transistor when you take these measurements because  $\beta$ ,  $g_m$  and  $r_{\pi}$  are only defined in the forward active region; consider monitoring the collector voltage as you take your data. Check your results for self consistency: what's the relation between  $r_{\pi}$  and  $g_m$ ?  $I_C$  and  $g_m$ ? Also compare your results against the 2N3904 datasheet on the course website (don't just use a random datasheet from the internet). Note that  $h_{fe}$  is commonly used synonym for  $\beta$ .
- 3. Put your transistor in the lab's curve tracer and capture the curve tracer data. Extract the Early Voltage,  $V_A$  from the curve tracer data and compare it to the datasheet.
- 4. For extra credit you may repeat steps 2-4 with a 2N3906 transistor.

**Required Data**: Diode drop measurement and explanation. Curves of  $\beta$ ,  $g_m$ ,  $V_{CE,SAT}$  and  $r_{\pi}$  vs.  $I_C$  with appropriate summaries of experimental setup and equivalent circuit models for each measurement. Curve tracer output and  $V_A$  estimate.